

Three Phase Rectifier Bridge

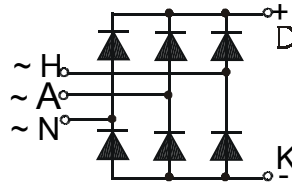
PSD 67

$$I_{dAV} = 68 \text{ A}$$

$$V_{RRM} = 600-1600 \text{ V}$$

Preliminary Data Sheet

| V_{RSM} V_{DSM} (V) | V_{RRM} V_{DRM} (V) | Type |
|-------------------------------|-------------------------------|-----------|
| 700 | 600 | PSD 67/06 |
| 900 | 800 | PSD 67/08 |
| 1300 | 1200 | PSD 67/12 |
| 1500 | 1400 | PSD 67/14 |
| 1700 | 1600 | PSD 67/16 |



Features

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- Package with DCB ceramic base plate
- Isolation voltage 3000 V~
- Planar glass passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering
- UL registered, E 148688

Applications

- Supplies for DC power equipment
- Input rectifier for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- High power density
- Small and light weight

| Symbol | Test Conditions | Maximum Ratings |
|---------------|--|----------------------|
| I_{dAV}^* | $T_C = 100 \text{ }^\circ\text{C}$, (per module) | 68 A |
| I_{FSM} | $T_{VJ} = 45 \text{ }^\circ\text{C}$ t = 10 ms (50 Hz), sine | 300 A |
| | $V_R = 0$ t = 8.3 ms (60 Hz), sine | 320 A |
| | $T_{VJ} = T_{VJM}$ t = 10 ms (50 Hz), sine | 260 A |
| | $V_R = 0$ t = 8.3 ms (60 Hz), sine | 280 A |
| $\int i^2 dt$ | $T_{VJ} = 45 \text{ }^\circ\text{C}$ t = 10 ms (50 Hz), sine | 450 A ² s |
| | $V_R = 0$ t = 8.3 ms (60 Hz), sine | 425 A ² s |
| | $T_{VJ} = T_{VJM}$ t = 10 ms (50 Hz), sine | 340 A ² s |
| | $V_R = 0$ t = 8.3 ms (60 Hz), sine | 325 A ² s |
| T_{VJ} | | -40... + 150 °C |
| T_{VJM} | | 150 °C |
| T_{stg} | | -40... + 125 °C |
| V_{ISOL} | 50/60 Hz, RMS t = 1 min | 2500 V~ |
| | $I_{ISOL} \leq 1 \text{ mA}$ t = 1 s | 3000 V~ |
| M_d | Mounting torque (M4) | 1.5 - 1.8 Nm |
| | | 14 - 16 lb.in. |
| Weight | typ. | 10 g |

| Symbol | Test Conditions | Characteristic Value |
|------------|---|----------------------|
| I_R | $V_R = V_{RRM}$, $T_{VJ} = T_{VJM}$ | ≤ 3 mA |
| | $V_R = V_{RRM}$, $T_{VJ} = 25 \text{ }^\circ\text{C}$ | ≤ 0.5 mA |
| V_F | $I_F = 55 \text{ A}$, $T_{VJ} = 25 \text{ }^\circ\text{C}$ | ≤ 1.46 V |
| V_{TO} | For power-loss calculations only | 0.8 V |
| r_T | | 13 mΩ |
| R_{thJC} | per diode; DC | 1.1 K/W |
| | per module | 0.18 K/W |
| R_{thJK} | per diode; DC | 1.6 K/W |
| | per module | 0.27 K/W |
| d_s | Creeping distance on surface | 11.2 mm |
| d_A | Creeping distance in air | 9.7 mm |
| a | Max. allowable acceleration | 50 m/s ² |

Data according to IEC 60747 refer to a single diode unless otherwise stated
* - for resistive load at bridge output

Used solder not Pb free!

Package style and outline

Dimensions in mm (1mm = 0.0394")

